Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-388-0021

Inclosure Material:
Ceramic
Overall Length:
1.225 inches
Function For Which Designed:
Switching
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, dc
Power Rating Per Characteristic:
3.0 kilowatts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
3.0
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Test Features:
Screened to 580-0629-002
Test Data Document:
13499-922-6120 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0